

BRCS1C5P06MAQ

Rev.A Jan.-2025



DATA SHEET

SOT-23 P

P- CHANNEL MOSFET in a SOT-23 Plastic Package.

AEC-Q101

Ultra Low on-resistance. fast switching. Low on voltage, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

PWM

PWM application & Load switch, Meet the stringent requirements of automotive applications.

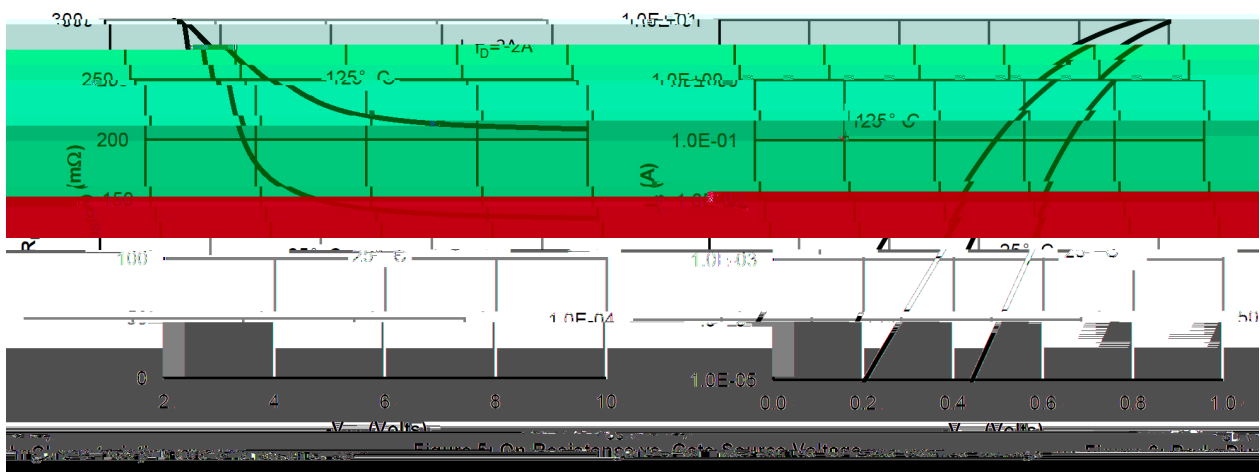
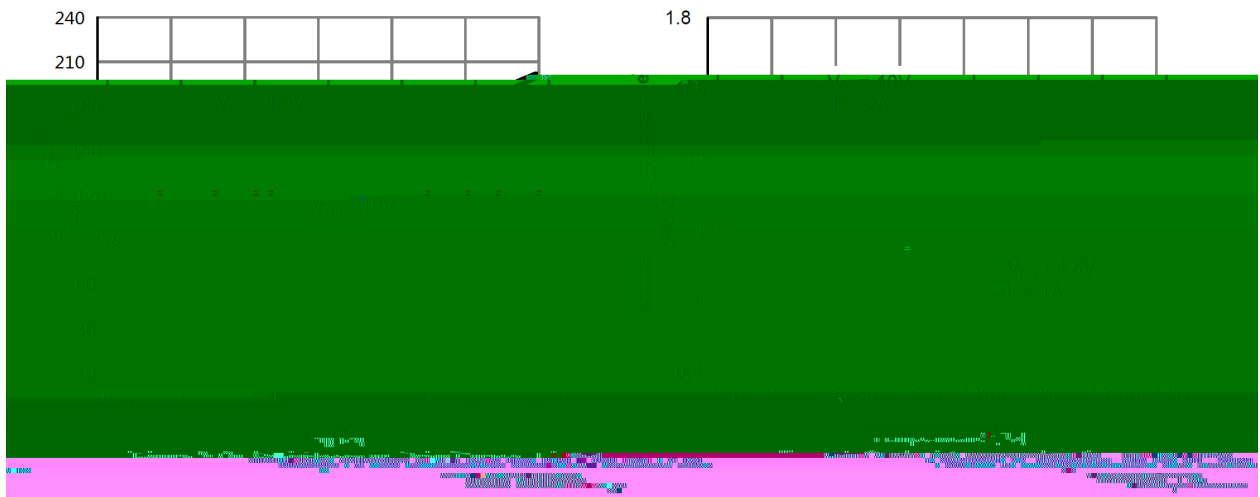
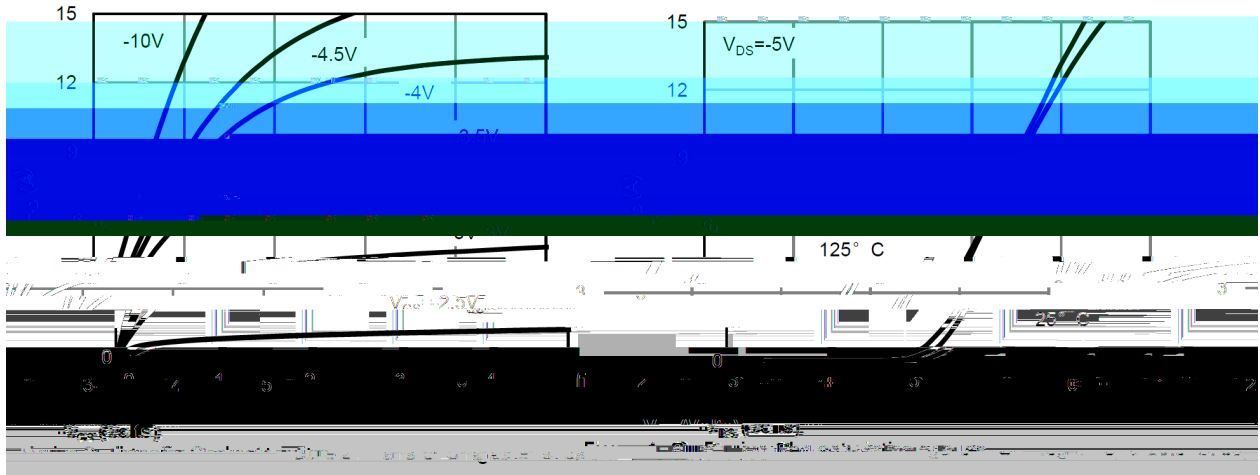
/ Absolute Maximum Ratings(Ta=25)

Parameter		Symbol	Rating	Unit
Drain–Source Voltage		V_{DSS}	-60	V
Gate–Body Leakage Voltage		V_{GSS}	± 20	V
Drain Current – Continuous		I_D	-2.3	A
Pulsed Drain Current		I_{DM}	-9	A
Power Dissipation		P_D	1.25	W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 150	
Maximum Junction-to-Ambient	t 10s	R_{JA}	72	/W
Maximum Junction-to-Ambient	Steady-State		100	/W
Maximum Junction-to-Lead	Steady-State	R_{JL}	64	/W

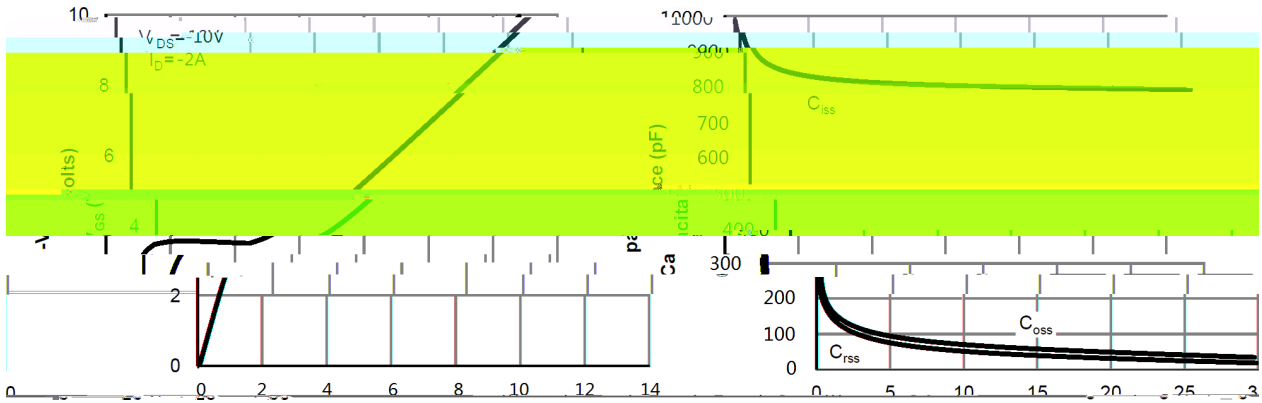
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain–Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V$ $I_D=-250\mu A$	-60	-75		V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1	-1.9	-2.5	V
Static Drain–Source On–Resistance	$R_{DS(on)}$	$V_{GS}=-10V$ $I_D=-2A$		135	150	m
		$V_{GS}=-4.5V$ $I_D=-1A$		160	200	m
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-60V$ $V_{GS}=0V$			-1.0	μA
Gate-Body leakage current	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 100	nA
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=-1A$ $T_J=25$			-1.2	V
Gate resistance	R_g	f=1MHz		6.5		
Input Capacitance	C_{iss}	$V_{DS}=-25V$ $V_{GS}=0V$ f=1.0MHz		800		pF
Output Capacitance	C_{oss}			45		
Reverse Transfer Capacitance	C_{rss}			35		
Total Gate Charge	$Q_{g(-10V)}$	$V_{DS}=-10V$ $V_{GS}=-10.0V$ $I_D=-2A$		12.3		nC
Total Gate Charge	$Q_{g(-4.5V)}$			6.3		
Gate-to-Source Charge	Q_{gs}			1.6		
Gate-to-Drain Charge	Q_{gd}			2.4		
Turn–On Delay Time	$t_{d(on)}$	$V_{DS}=-10V$ $V_{GS}=-10V$ $R_L=5.4$ $R_{GEN}=3$		12		ns
Turn–On Rise Time	t_r			20		
Turn–Off Delay Time	$t_{d(off)}$			20		
Turn–Off Fall Time	t_f			25		

/ Electrical Characteristic Curve



/ Electrical Characteristic Curve



V_{ds} (Volts) Q_g (nC) Capacitance Characteristics Figure 7: Gate-Charge Characteristics Figure 8: Capacitance Characteristics

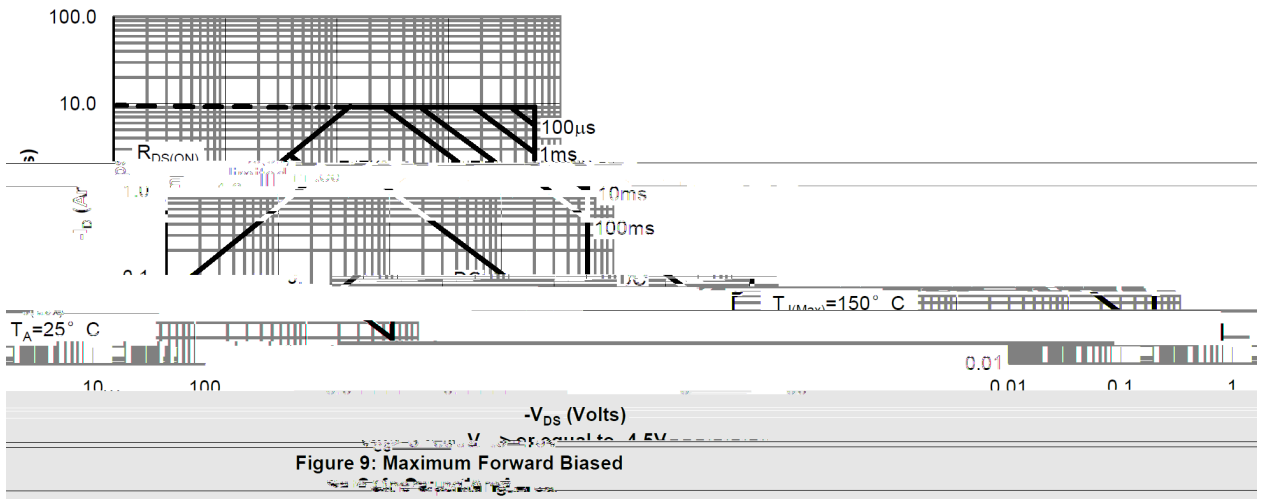


Figure 9: Maximum Forward Biased

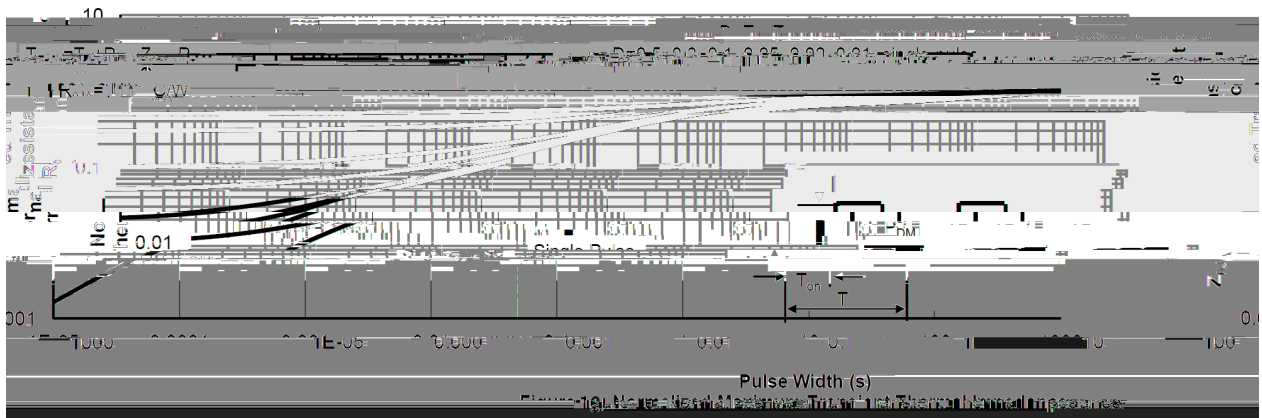
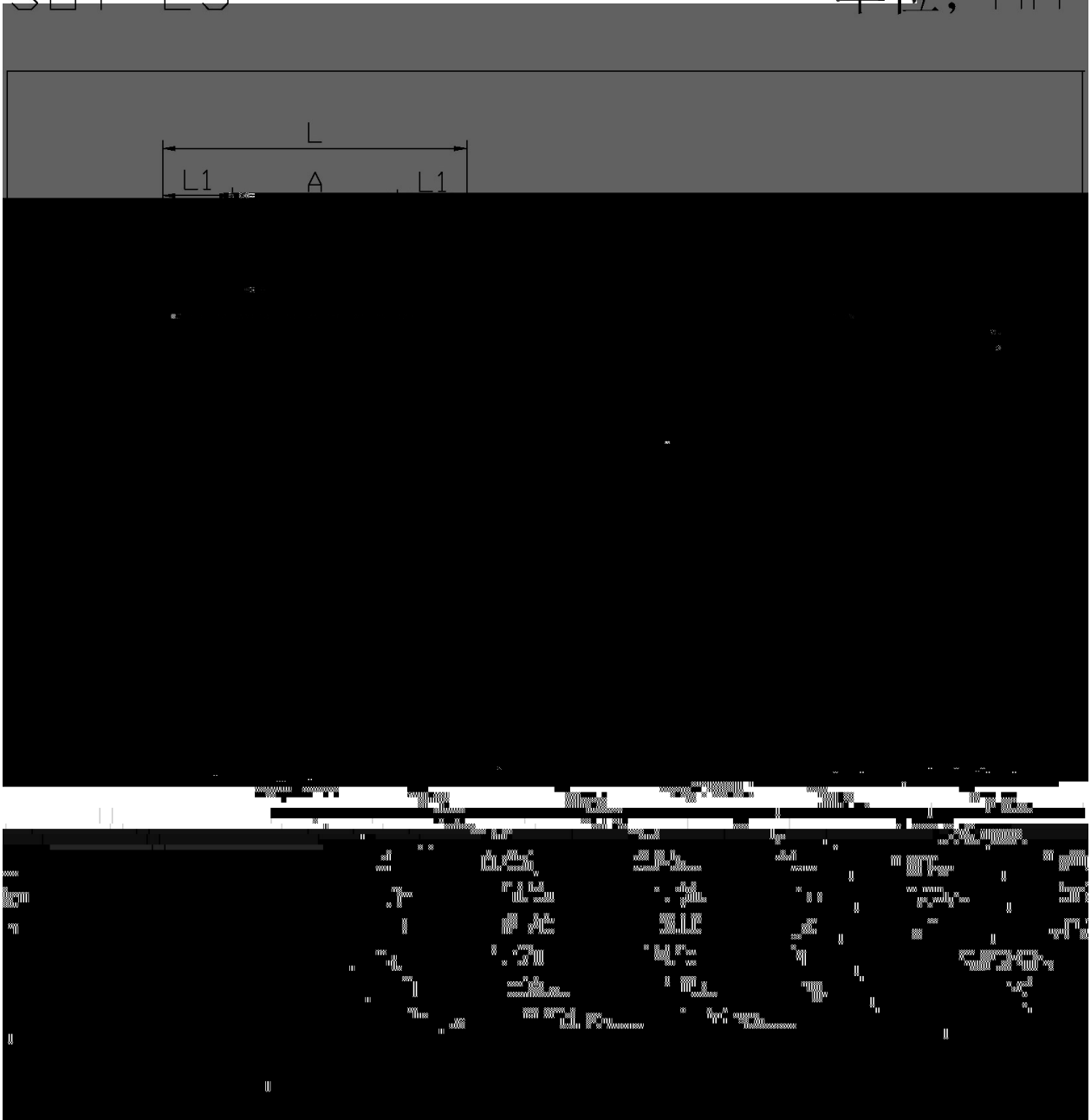


Figure 10: Normalized Maximum Turn-On and Turn-Off Times

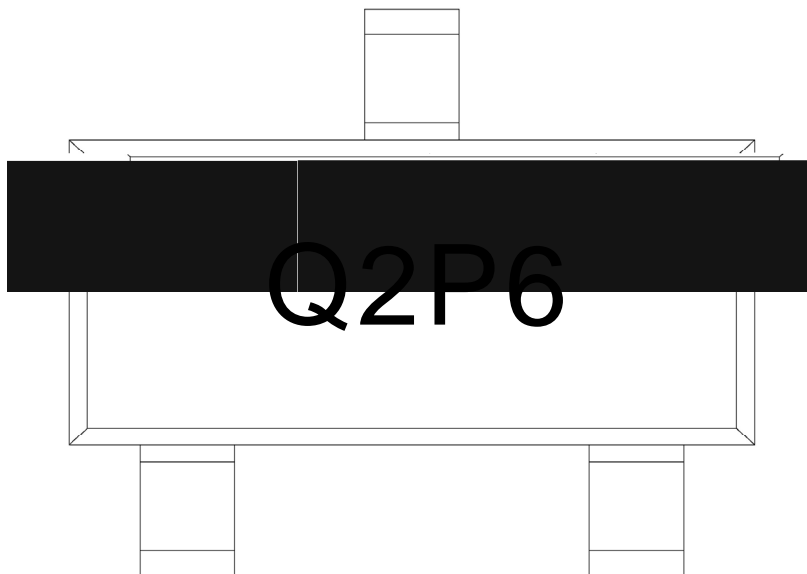
/ Package Dimensions

SOT-23

单位: mm



/ Marking Instructions



Q

2P6

Note:

Q: Automobile halogen-free product Code

2P6: Product Type Code

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